

20 V, N-channel Trench MOSFET 28 June 2016

Product data sheet

### 1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a leadless ultra small DFN1006-3 (SOT883) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

### 2. Features and benefits

- Low leakage current
- Leadless ultra small SMD plastic package: 1.0 × 0.6 × 0.48 mm
- ElectroStatic Discharge (ESD) protection > 1 kV HBM
- Drain-source on-state resistance R<sub>DSon</sub> = 470 mΩ

### 3. Applications

- Relay driver
- High-speed line driver
- Low-side load switch
- Switching circuits

### 4. Quick reference data

Table 1. Quick reference data								
Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	20	V	
V <sub>GS</sub>	gate-source voltage			-8	-	8	V	
I <sub>D</sub>	drain current	V <sub>GS</sub> = 4.5 V; T <sub>amb</sub> = 25 °C	[1]	-	-	0.6	А	
Static characte	eristics			·			_	
R <sub>DSon</sub>	drain-source on-state resistance	$V_{GS}$ = 4.5 V; I <sub>D</sub> = 0.6 A; T <sub>j</sub> = 25 °C		-	470	620	mΩ	

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 1 cm<sup>2</sup>.

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### 5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	1	D
2	S	source	2 2 3	
3	D	drain	Transparent top view DFN1006-3 (SOT883)	G G S 017aaa255

### 6. Ordering information

Table 3. Ordering in	formation					
Type number	Package	je				
	Name	Description	Version			
PMZ600UNEL	DFN1006-3	DFN1006-3: leadless ultra small plastic package; 3 solder lands	SOT883			

### 7. Marking

Table 4. Marking codes	
Type number	Marking code
PMZ600UNEL	L3

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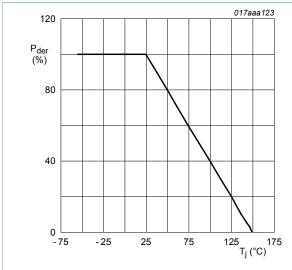
### 8. Limiting values

#### Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	20	V
V <sub>GS</sub>	gate-source voltage			-8	8	V
I <sub>D</sub>	drain current	$V_{GS}$ = 4.5 V; $T_{amb}$ = 25 °C	[1]	-	0.6	А
		$V_{GS}$ = 4.5 V; $T_{amb}$ = 100 °C	[1]	-	0.4	А
I <sub>DM</sub>	peak drain current	$T_{amb}$ = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	2.5	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C	[2]	-	360	mW
			[1]	-	715	mW
		T <sub>sp</sub> = 25 °C		-	2700	mW
Tj	junction temperature			-55	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C
Source-dra	in diode	,	1			_
I <sub>S</sub>	source current	T <sub>amb</sub> = 25 °C	[1]	-	0.4	А

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 1 cm<sup>2</sup>.
- [2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.





$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$

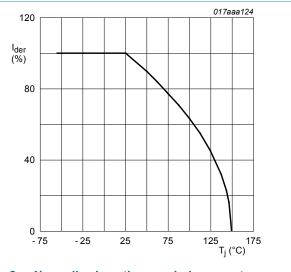


Fig. 2. Normalized continuous drain current as a function of junction temperature

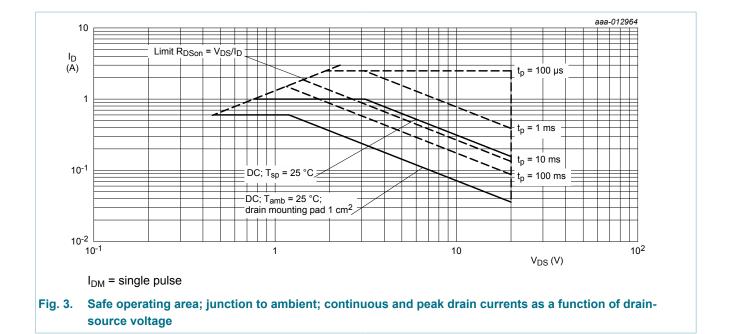
$$I_{der} = \frac{I_D}{I_D(25^{\circ}C)} \times 100 \%$$

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### 9. Thermal characteristics

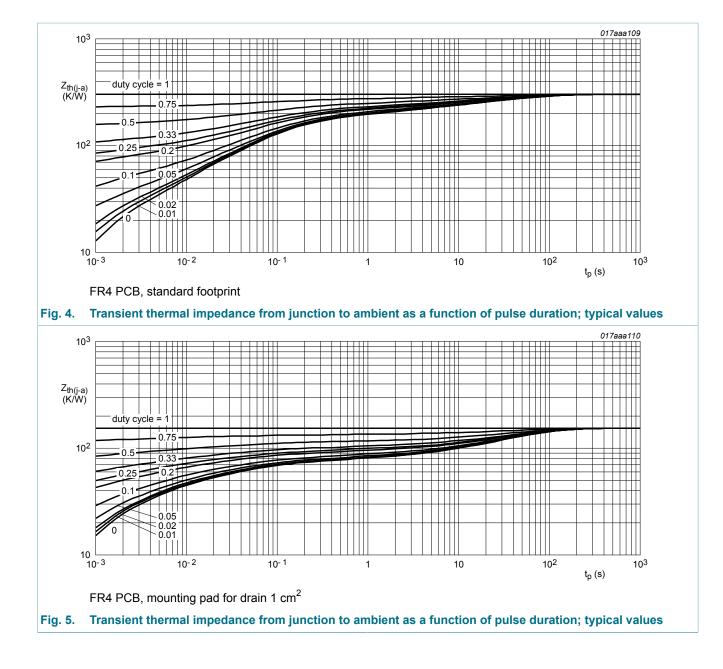
Table 6. Thermal characteristics								
Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
ui(-a)	thermal resistance in from junction to ambient	in free air	[1]	-	305	360	K/W	
			[2]	-	150	175	K/W	
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	-	40	K/W	

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm<sup>2</sup>.

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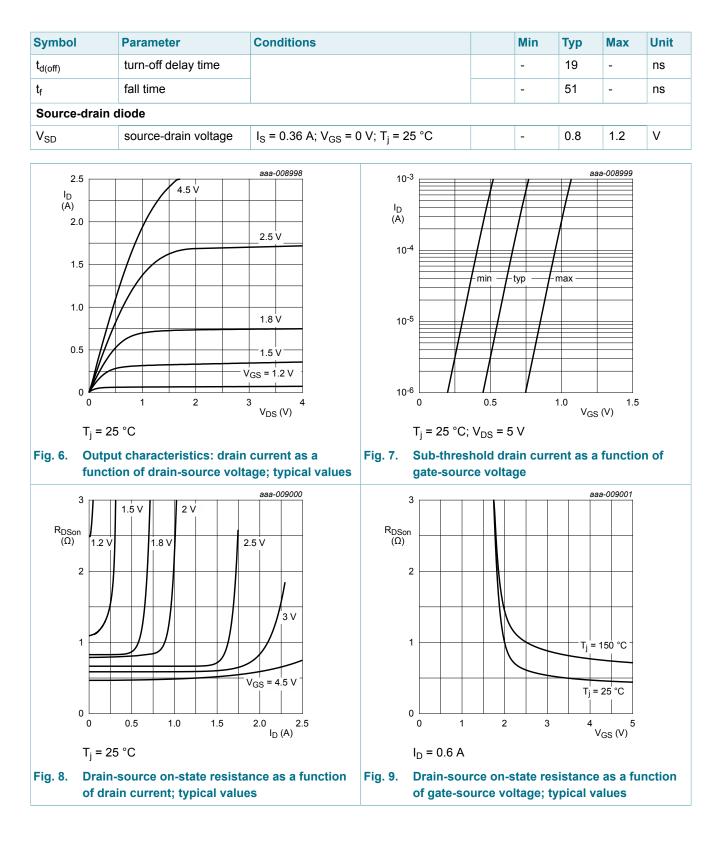
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### **10. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	cteristics	!			_	
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	I <sub>D</sub> = 250 μA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	20	-	-	V
V <sub>GSth</sub>	gate-source threshold voltage	I <sub>D</sub> = 250 μA; V <sub>DS</sub> =V <sub>GS</sub> ; T <sub>j</sub> = 25 °C	0.45	0.7	0.95	V
I <sub>DSS</sub>	drain leakage current	$V_{DS}$ = 20 V; $V_{GS}$ = 0 V; $T_j$ = 25 °C	-	-	1	μA
		V <sub>DS</sub> = 20 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 150 °C	-	-	10	μA
		V <sub>DS</sub> = 5 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	25	nA
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 8 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	10	μA
		V <sub>GS</sub> = -8 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	-10	μA
		$V_{GS}$ = 4.5 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	1	μA
		V <sub>GS</sub> = -4.5 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	-1	μA
		$V_{GS}$ = 1.8 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	50	nA
		V <sub>GS</sub> = -1.8 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	-50	nA
R <sub>DSon</sub>	drain-source on-state	V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 0.6 A; T <sub>j</sub> = 25 °C	-	470	620	mΩ
	resistance	$V_{GS}$ = 4.5 V; I <sub>D</sub> = 0.6 A; T <sub>j</sub> = 150 °C	-	760	1000	mΩ
		V <sub>GS</sub> = 2.5 V; I <sub>D</sub> = 0.5 A; T <sub>j</sub> = 25 °C	-	620	850	mΩ
		V <sub>GS</sub> = 1.8 V; I <sub>D</sub> = 0.1 A; T <sub>j</sub> = 25 °C	-	845	1300	mΩ
		V <sub>GS</sub> = 1.5 V; I <sub>D</sub> = 10 mA; T <sub>j</sub> = 25 °C	-	1125	3000	mΩ
		$V_{GS}$ = 1.2 V; I <sub>D</sub> = 1 mA; T <sub>j</sub> = 25 °C	-	2210	-	mΩ
9fs	forward transconductance	$V_{DS}$ = 5 V; I <sub>D</sub> = 0.6 A; T <sub>j</sub> = 25 °C	-	1	-	S
R <sub>G</sub>	gate resistance	f = 1 MHz	-	34	-	Ω
Dynamic ch	aracteristics	1				
Q <sub>G(tot)</sub>	total gate charge	$V_{DS}$ = 10 V; I <sub>D</sub> = 0.6 A; V <sub>GS</sub> = 4.5 V;	-	0.4	0.7	nC
Q <sub>GS</sub>	gate-source charge	T <sub>j</sub> = 25 °C	-	0.1	-	nC
Q <sub>GD</sub>	gate-drain charge		-	0.1	-	nC
C <sub>iss</sub>	input capacitance	$V_{DS}$ = 10 V; f = 1 MHz; $V_{GS}$ = 0 V;	-	21.3	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C	-	5.4	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	4.2	-	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS}$ = 10 V; I <sub>D</sub> = 0.6 A; V <sub>GS</sub> = 4.5 V;	-	5.6	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	9.2	-	ns

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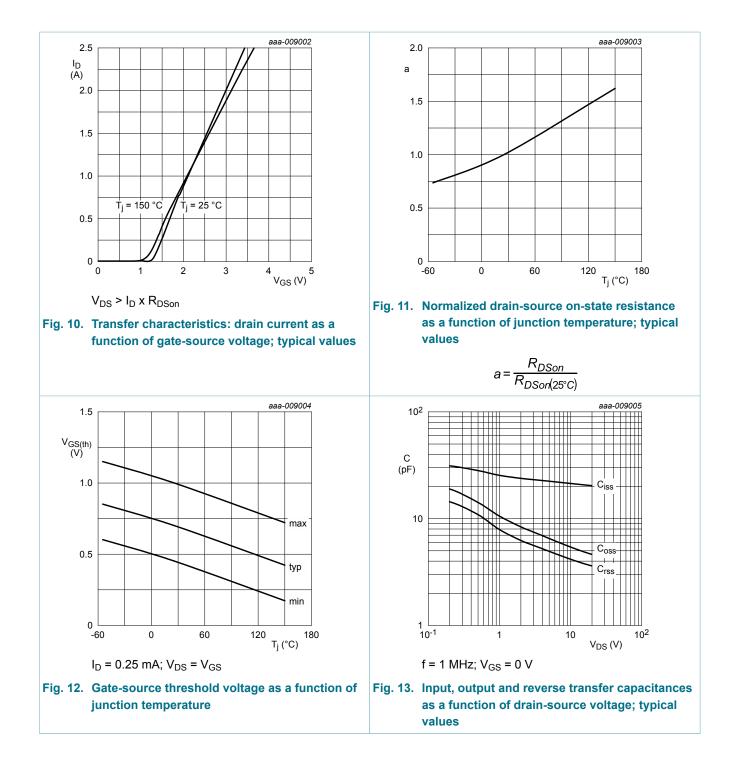
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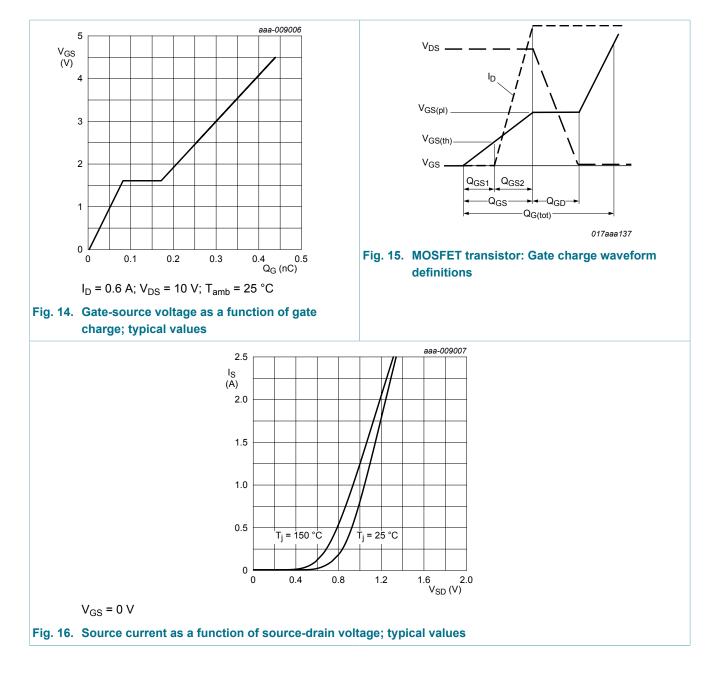
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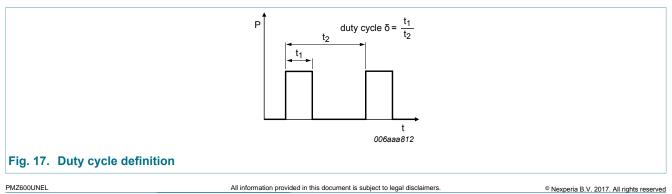
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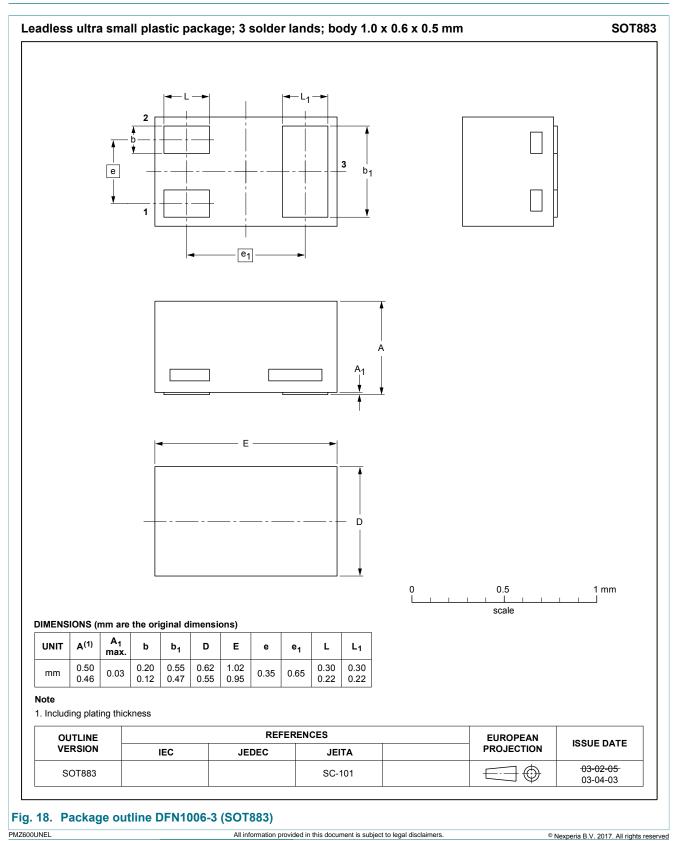


### **11. Test information**



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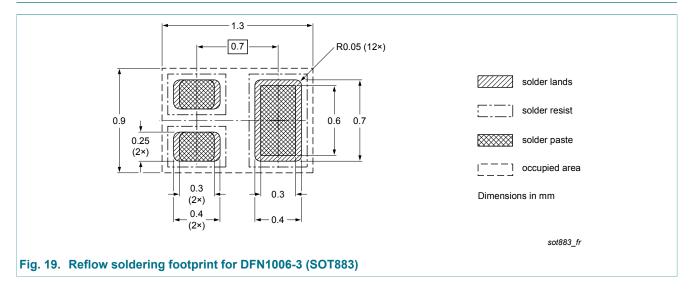
### 12. Package outline



Product data sheet

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### 13. Soldering



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### 14. Revision history

Table 8. Revision his	story			
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMZ600UNEL v.1	20160628	Product data sheet	-	-

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#### 15. Legal information

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Document status [1][2]	Product status [ <u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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#### 20 V, N-channel Trench MOSFET

### **16. Contents**

1	General description	1
2	Features and benefits	1
3	Applications	1
4	Quick reference data	1
5	Pinning information	2
6	Ordering information	2
7	Marking	2
8	Limiting values	3
9	Thermal characteristics	4
10	Characteristics	6
11	Test information	9
12	Package outline	10
13	Soldering	11
14	Revision history	12
15	Legal information	13
15.1	Data sheet status	13
15.2	Definitions	13
15.3	Disclaimers	13
15.4	Trademarks	14

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